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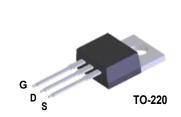
FQP17P06 P-Channel QFET[®] MOSFET - 60 V, - 17 A, 120 mΩ

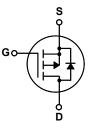
Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor[®]'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 17 A, 60 V, $\mathsf{R}_{DS(on)}$ = 120 m Ω (Max.) @ V_{GS} = 10 V, ID = 8.5 A
- Low Gate Charge (Typ.21 nC)
- Low Crss (Typ. 80 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Symbol	Parameter		FQP17P06	Unit	
V _{DSS}	Drain-Source Voltage Drain Current - Continuous (T _C = 25°C)			-60	V
I _D			°C)	-17	A
		- Continuous (T _C = 10	O°C)	-12	Α
I _{DM}	Drain Current	- Pulsed	(Note 1)	-68	А
V _{GSS}	Gate-Source Voltage			± 25	V
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	300	mJ
I _{AR}	Avalanche Current		(Note 1)	-17	А
E _{AR}	Repetitive Avalanche Energy		(Note 1)	7.9	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	-7.0	V/ns
P _D	Power Dissipation (T _C = 25°C)			79	W
	- Derate above 25°C			0.53	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +175	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds			300	°C
۰L				500	C

Thermal Characteristics

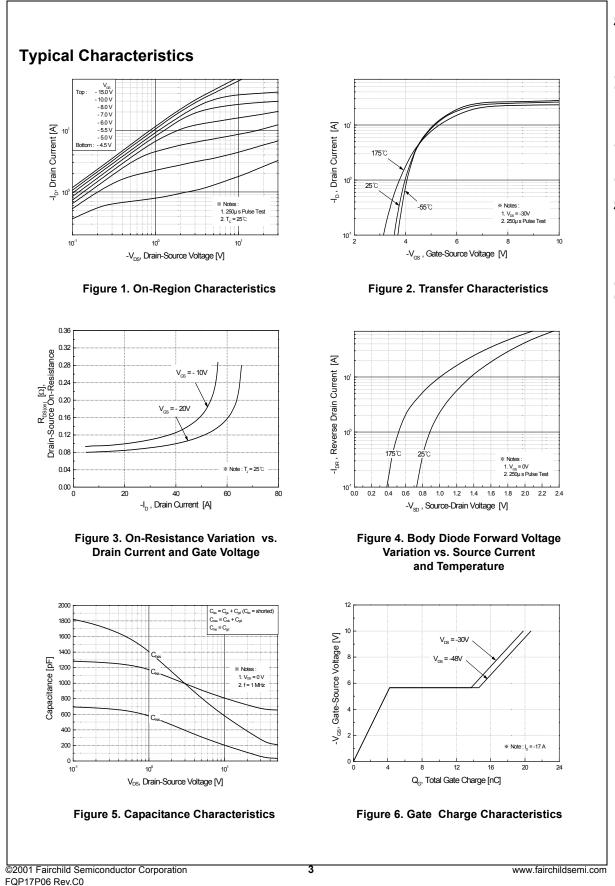
Symbol	Parameter	FQP17P06	Unit	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	1.9	°C/W	
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.5	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

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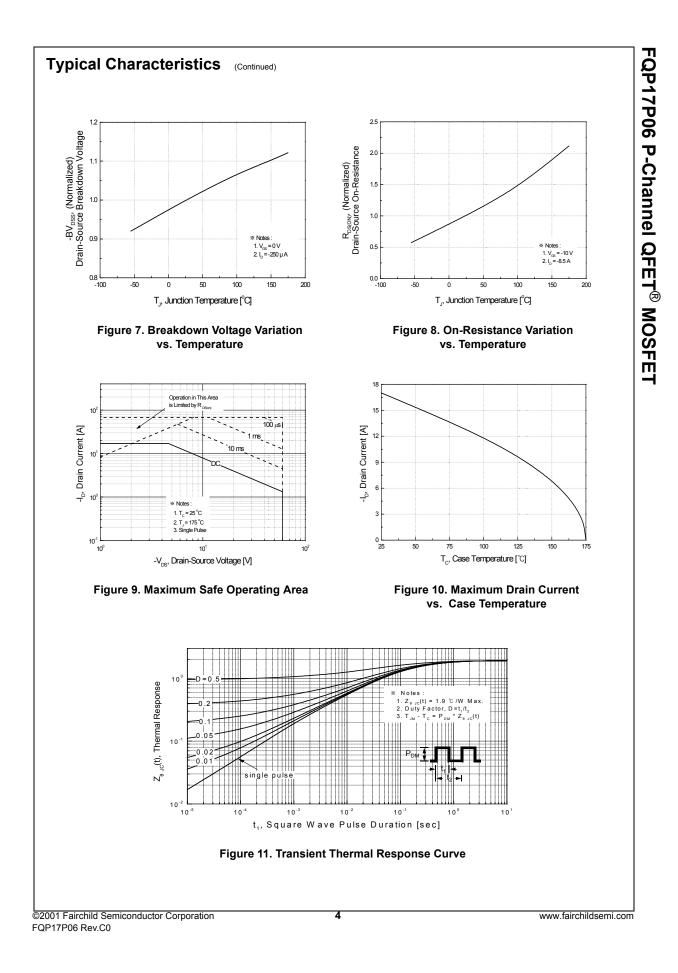
March 2013

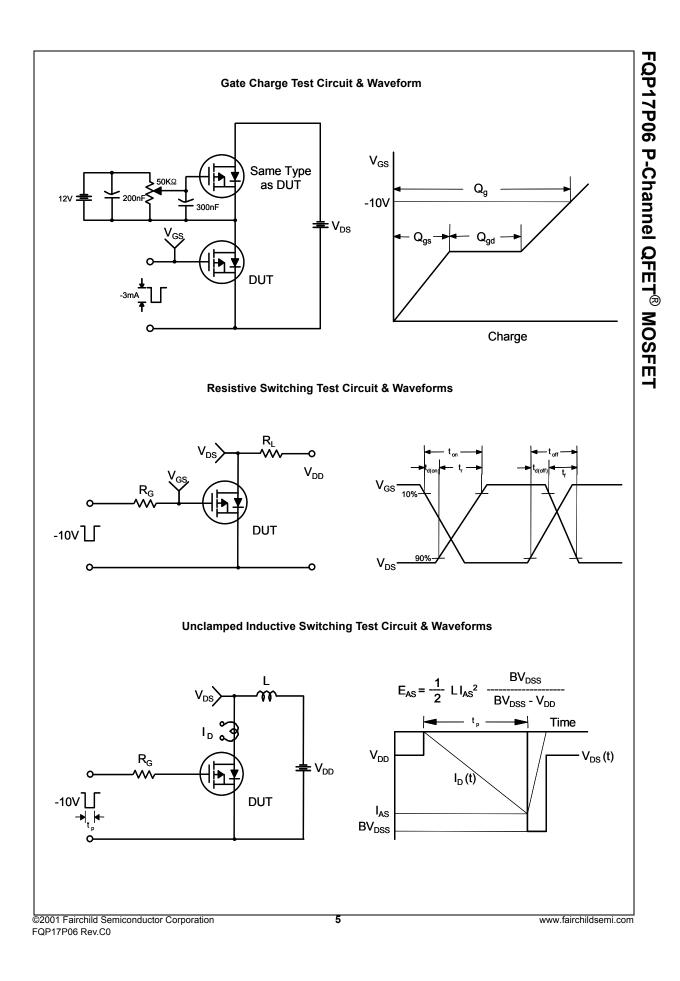
	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS} Drain-Source Breakdown Voltage		V _{GS} = 0 V, I _D = -250 μA	-60			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		-0.06		V/°C
I _{DSS}	Zara Cata Valtaga Drain Current	V _{DS} = -60 V, V _{GS} = 0 V			-1	μA
	Zero Gate Voltage Drain Current	V _{DS} = -48 V, T _C = 150°C			-10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = -25 V, V_{DS} = 0 V			-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = 25 V, V_{DS} = 0 V			100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-2.0		-4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance $V_{GS} = -10 \text{ V}, I_D = -8.5 \text{ A}$			0.094	0.12	Ω
9 _{FS}	Forward Transconductance	V _{DS} = -30 V, I _D = -8.5 A		9.3		S
	I	L		1		
-	ic Characteristics			1	1	1
C _{iss}	Input Capacitance $V_{DS} = -25 V, V_{GS} = 0 V,$			690	900	pF
C _{oss}	Output Capacitance			325	420	pF
C _{rss}	Reverse Transfer Capacitance			80	105	pF
t _{d(on)} t _r	i ng Characteristics Turn-On Delay Time Turn-On Rise Time	$V_{DD} = -30 \text{ V}, \text{ I}_{D} = -8.5 \text{ A},$		13 100	35 210	ns ns
t _{d(off)}	Turn-Off Delay Time	R _G = 25 Ω		22	55	ns
t _f	Turn-Off Fall Time	(Note 4)		60	130	ns
Q _g	Total Gate Charge	V _{DS} = -48 V, I _D = -17 A,		21	27	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -10 V$		4.2		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		10		nC
3-						
	Source Diode Characteristics an				-17	A
	Maximum Continuous Drain-Source Dic					A
I _S	Maximum Continuous Drain-Source Dic Maximum Pulsed Drain-Source Diode F				-68	
I _S I _{SM}	Maximum Pulsed Drain-Source Diode F	Forward Current			-68 -4 0	
I _S I _{SM} V _{SD}	Maximum Pulsed Drain-Source Diode F Drain-Source Diode Forward Voltage	Forward Current $V_{GS} = 0 V, I_S = -17 A$		 92	-4.0	V
I _S I _{SM}	Maximum Pulsed Drain-Source Diode F	Forward Current		 92 0.32		

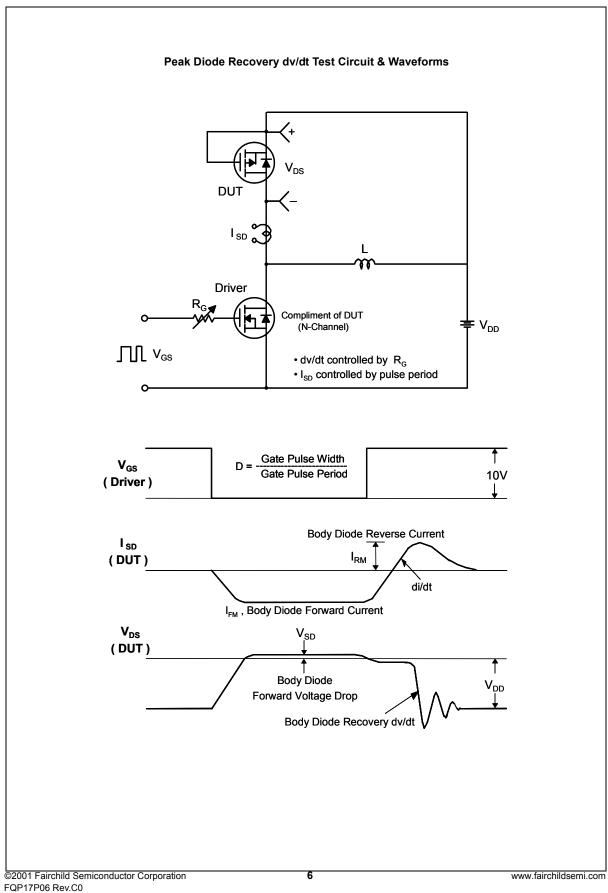
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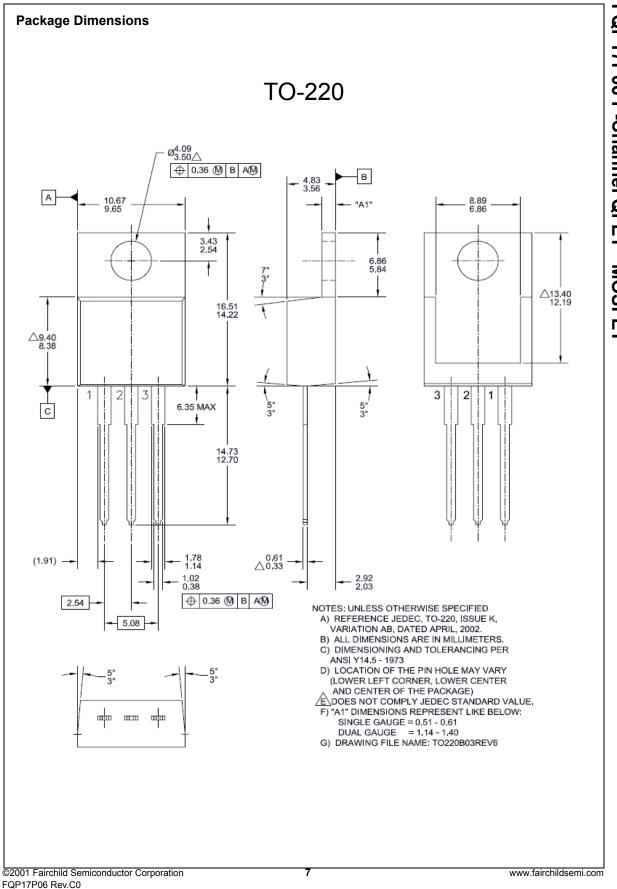


FQP17P06 P-Channel QFET® MOSFET













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